



DDR SDRAM SO-DIMM MODULE, 2.5V

512MByte - 64MX64

AVK6464U39C5266K6

FEATURES

JEDEC Compliant DDR 266MHz PC2100 Version 1.0

- Clock frequency: 133MHz with CAS latency 2.5
- 256 byte serial EEPROM
- Data input and output masking
- Programmable burst length: 2, 4, 8
- Programmable burst type: sequential and interleave
- Programmable CAS latency: 2.5
- Auto refresh and self refresh capability
- Gold card edge fingers
- 8K refresh per 64ms
- Low active and standby current consumption
- SSTL-2 compatible inputs and outputs
- Decoupling capacitors at each memory device
- Double-sided module
- 1.25 inch height

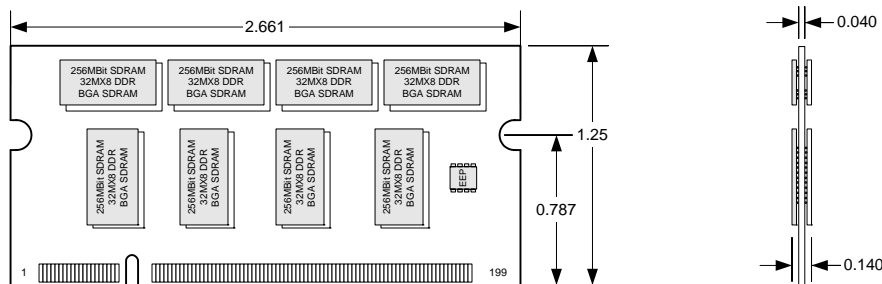
DESCRIPTION

The AVK6464U39C5266K6 family consists of Unbuffered DDR SDRAM SODIMM memory module. This module is JEDEC-standard 200-pin, small-outline, dual in-line memory module. A 256 byte serial EEPROM on board can be used to store module information such as timing, configuration, density, etc.

The AVK6464U39C5266K6 memory module is 512MByte and organized as a 64MX64 array using (16) 32MX8 (4 internal banks) SDRAMs in BGA packages.

All memory modules are fabricated using the latest technology design, six-layer printed circuit board substrate construction with low ESR decoupling capacitors on-board for high reliability and low noise.

PHYSICAL DIMENSIONS



All gray ICs are on the front side of the module, and all white ICs are on the back side of the module.

BGA Package

Avant Ordering Guides

AV	K	64	64	U	39	C	5	266	K	6
INVENTORY	MOD. TYPE	ORG.	DENSITY	PARITY	TYPE	VOLT.	FEATURE	SPEED	MODE	REV
AV = AVANT	K = 200-PIN SO-DIMM	64=X64	64=64M	U=UNBUFFERED	39 = 8Mx8x4	C = 2.5V	5=CAS LATENCY 2.5	266MHZ	K=DDR SDRAM	REV=6

Other options may be available. Call for specific part number information on options not listed.



Avant™ Technology LP., reserves the right to change products or specifications without notice.